

RN1417(TE85L,F)

RN1417(TE85L,F) Information

www.interent.com	RN1417(TE85L,F) Toshiba Semiconductor and Storage Discrete Semiconductor Products Transistors - Bipolar (BJT) - Single, Pre-Biased TRANS PREBIAS NPN 0.2W S-MINI TO-236-3, SC-59, SOT-23-3 For the pricing/inventory/lead time, please contact	
For Reference Only	us Website: https://www.heisener.com E-mail: salesdept@heisener.com	Request a Quote

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.



RN1417(TE85L,F) Specifications

Manufacturer Part Number	RN1417(TE85L,F)	
Manufacturer	Toshiba Semiconductor and Storage	
Category	Discrete Semiconductor Products	
	Transistors - Bipolar (BJT) - Single, Pre-Biased	
Package	TO-236-3, SC-59, SOT-23-3	
Series	-	
Transistor Type	NPN - Pre-Biased	
Current - Collector (Ic) (Max)	100mA	
Voltage - Collector Emitter Breakdown (Max)	50V	
Resistor - Base (R1) (Ohms)	10k	
Resistor - Emitter Base (R2) (Ohms)	4.7k	
DC Current Gain (hFE) (Min) @ Ic, Vce	30 @ 10mA, 5V	
Vce Saturation (Max) @ Ib, Ic	300mV @ 250µA, 5mA	
Current - Collector Cutoff (Max)	500nA	
Frequency - Transition	250MHz	
Power - Max	200mW	
Mounting Type	Surface Mount	
Package / Case	TO-236-3, SC-59, SOT-23-3	
Supplier Device Package	S-Mini	
	Report errors?	

RN1417(TE85L,F) Guarantees



Quality Guarantees

We provide 90 days warranty. * If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction. Our experienced sales team and tech support team back our services to satisfy all our customers.

RN1417(TE85L,F) Payment Methods



RN1417(TE85L,F) Shipping Methods



If you have any question about RN1417(TE85L,F), please do not hesitate to contact us! Website: https://www.heisener.com E-mail: salesdept@heisener.com